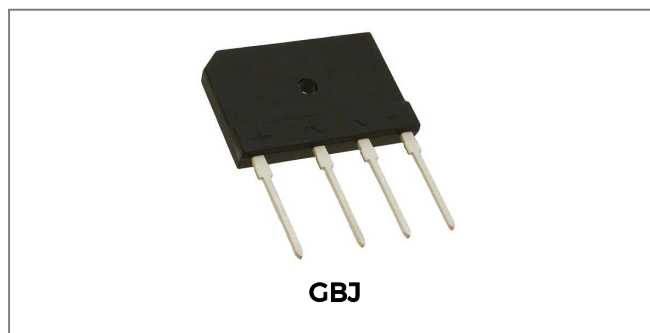


GBJ2506L

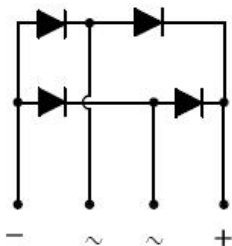
Single-Phase 25.0A Glass Passivated Bridge Rectifier



Features

- Glass passivated die construction
- Low forward voltage drop
- High current capability
- High surge current capability
- Plastic material-UL flammability 94V-0
- This is a Pb - Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Mechanical Data

- Case: GBJ, Molded plastic
- Terminals: Plated leads solderable per MIL-STD-202, Method 208
- Polarity: as marked on case
- Mounting Position: Any
- Lead Free: For RoHS / Lead Free Version
- Weight: 6.8 grams(approx)

Maximum Ratings @T_A=25°C unless otherwise specified

Type Number	Symbol	GBJ2506L	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_{DC}	600	V
RMS Reverse Voltage	V_{RMS}	420	V
Average Rectified Output Current (with heatsink Note 1) @T _C = 90°C (without heatsink)	$I_{(AV)}$	25 3.6	A
Peak Forward Surge Current, 8.3ms single half-sine-wave superimposed on rated load (JEDEC method)	I_{FSM}	450	A
I ² t Rating for Fusing (t<8.3ms)	I ² t	840.38	A ² s

Electrical Characteristics@T_A=25°C unless otherwise specified

Type Number	Symbol	GBJ2506L		Units
Forward Voltage @I _F =12.5A @I _F =25A	V _F	TYPE	MAX	V
		0.895 0.95	0.92 1.0	
Peak Reverse Current @T _A = 25°C At Rated DC Blocking Voltage @T _A = 125°C	I _{RM}	5.0 200		μA
Dielectric Strength	V _{ids}	2500		V
The proposed installation torque Max torque	T _{or}	Typ. 5.0 Max 8.0		Kgf.cm
Typical Junction Capacitance(Per Element) (Note 2)	C _J	200		pF

* Pulse width < 300 μs, duty cycle < 2%

Thermal-Mechanical Specifications:

Type Number	Symbol	GBJ2506L	Units
Typical Thermal Resistance	R _{θJC}	2.2	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Note: 1. Unit case mounted on aluminum plate heatsink.
2.Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

Ratings and Characteristics Curves

Fig. 1 Forward Current Derating Curve

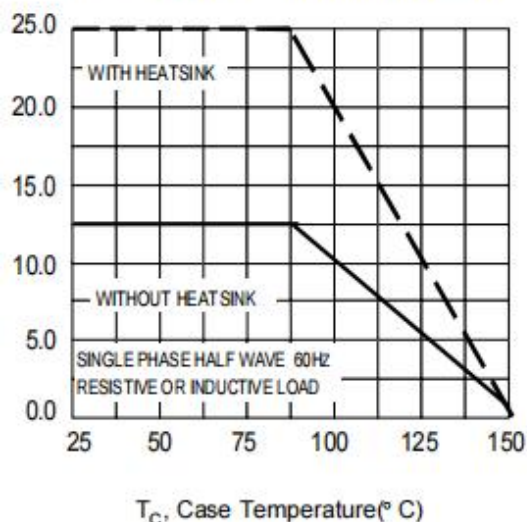


Fig. 2 Typ. Forward Characteristics

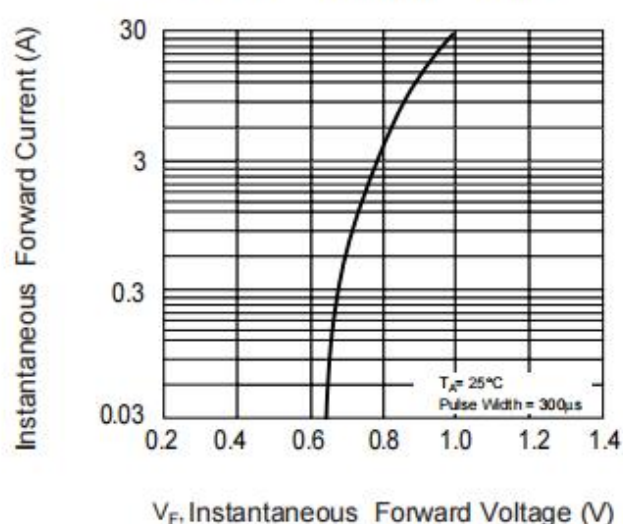


Fig.3 Maximum Peak Forward Surge Current

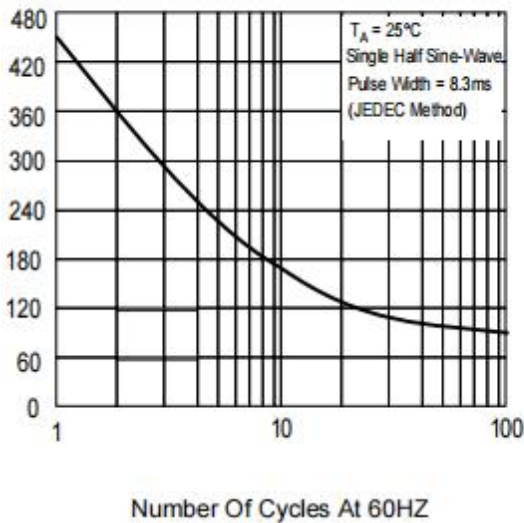


Fig . 4 Typical Junction Capacitance

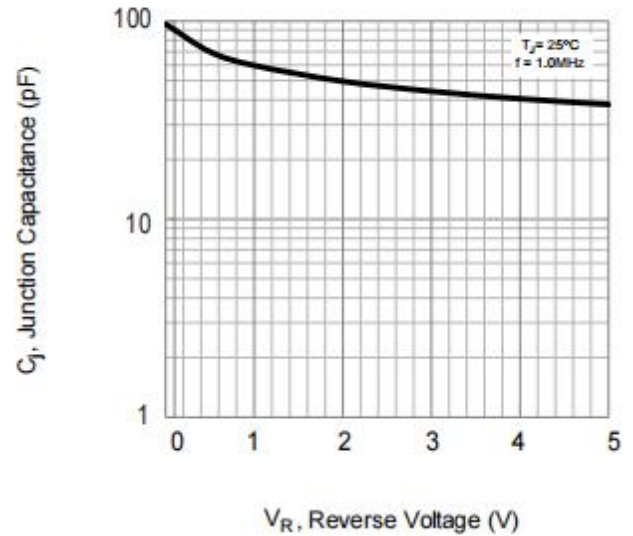
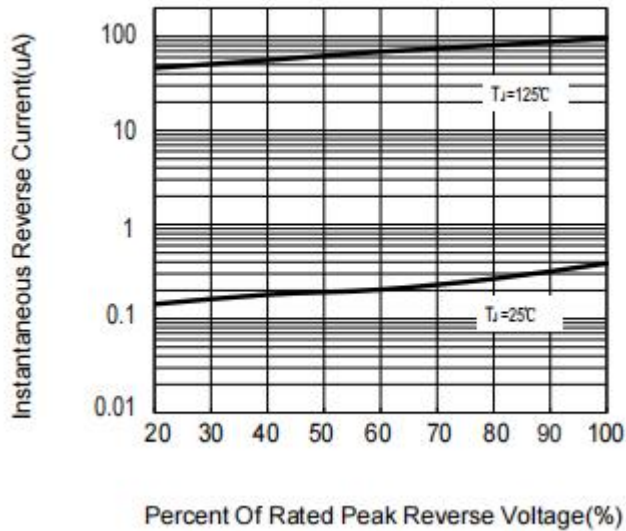


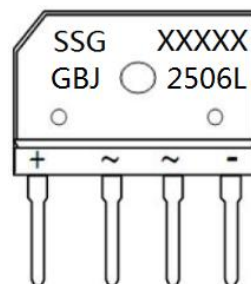
Fig.5 Typical Reverse Characteristics



Ordering Information

Device	Package	Plating	Shipping
GBJ2506L	GBJ(Pb-Free)	Pure Sn	15pcs / tube

Marking Diagram

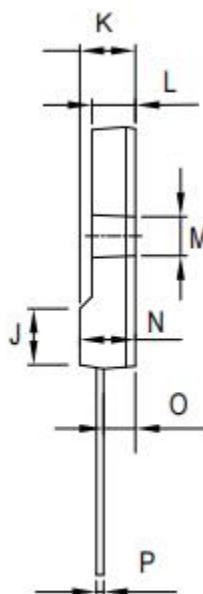
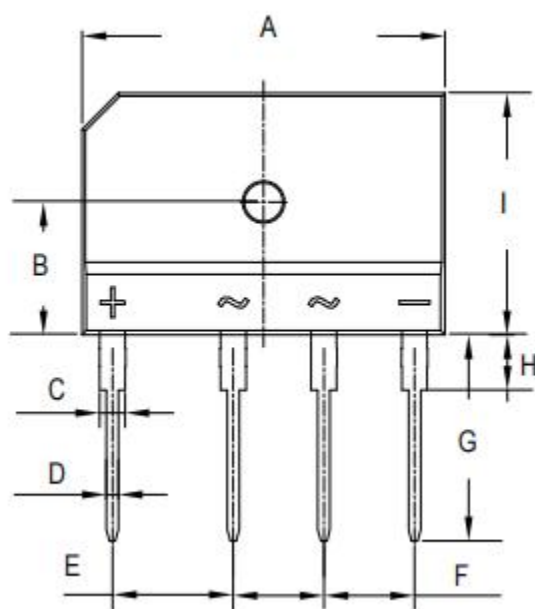


Where XXXXX is YYWWL

SSG = SSG
YY = Year
WW = Week
L = Lot Number
GBJ2506L = Type Number

Cautions: Molding resin
Epoxy resin UL94V-0

Mechanical Dimensions GBJ (Inches/Millimeters)



Dimensions	Millimeters		Inches	
	Min	Max	Min	Max
A	29.7	30.3	1.169	1.193
B	10.8	11.2	0.425	0.441
C	1.9	2.3	0.075	0.091
D	0.9	1.1	0.035	0.043
E	9.8	10.2	0.386	0.402
F	7.3	7.7	0.287	0.303
G	17.0	18.0	0.699	0.709
H	3.8	4.2	0.150	0.165
I	19.7	20.3	0.776	0.799
J	4.8	5.2	0.189	0.205
K	4.4	4.8	0.173	0.189
L	3.4	3.8	0.134	0.150
M	3.1	3.4	0.122	0.134
N	4.4	4.8	0.173	0.189
O	2.4	2.8	0.094	0.110
P	0.5	0.7	0.020	0.028

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